

SDS19D SWITCHING DIODE

High Voltage Switching Diode

General Description

General-purpose switching diodes, fabricated in planar technology, and packaged in small SOD-323 surface mounted device (SMD) packages.

Features and Benefits

- Silicon epitaxial planar diode
- · High switching speed
- · Low forward drop voltage and low leakage current
- "Green" device and RoHS compliant device
- Available in full lead (Pb)-free device



SOD-323





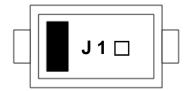
Applications

• Ultra high speed switching application

Ordering Information

Part Number	Marking Code	Package	Packaging
SDS19D	J1 □	SOD-323	Tape & Reel

Marking Information



J 1 = Specific Device Code

☐ = Year & Week Code Marking

= Color band denote cathode

Pinning Information

Pin	Description	Simplified Outline	Graphic Symbol
1	Cathode	1 2	
2	Anode		

Absolute Maximum Ratings (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Maximum repetitive peak reverse voltage	V_{RM}	120	V
Continuous reverse voltage	V_R	100	V
Maximum average forward rectified current	Io	200	mA
Maximum repetitive peak forward current	I _{FM}	400	mA
Non-repetitive peak forward surge current(t=10ms)	I _{FSM}	1.7	А
Power dissipation 1)	P _D	200	mW

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Thermal Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit
Thermal resistance, junction to ambient 1)	$R_{\text{th(j-a)}}$	625	°C/W
Operating junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 ~ 150	°C

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Electrical Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	V_{BR}	I _F =100uA	120	-	-	V
Forward drop voltage ²⁾	V_{F}	I _F =100mA	1.0	V		
	VF	I _F =200mA	-	-	1.25	V
Reverse leakage current 3)		V _R =100V	-	-	100	nA
	l _R	V _R =100V, Ta=150°C	-	-	100	uA
Total capacitance	Ст	V _R =0V, f=1MHz	-	-	5	pF
Reverse recovery time	t _{rr}	$I_F=I_R=30$ mA, $I_{rr}=3$ mA, $R_L=100$ Ω	-	-	50	ns

²⁾ Pulse test: t_P≤380 µs, Duty cycle≤2%

 $^{^{3)}}$ Pulse test: $t_P \le 5 ms$, Duty cycle $\le 2\%$

Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics

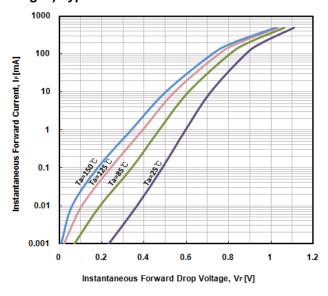


Fig. 2) Typical Reverse Characteristics

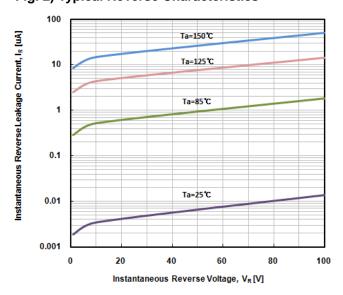


Fig. 3) Typical Total Capacitance Characteristics

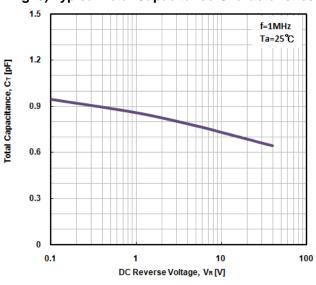


Fig. 4) Power Dissipation vs. Ambient Temperature

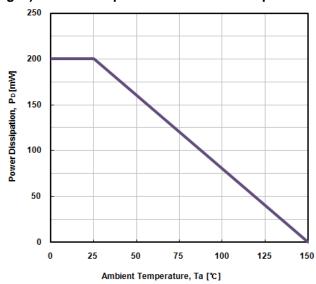
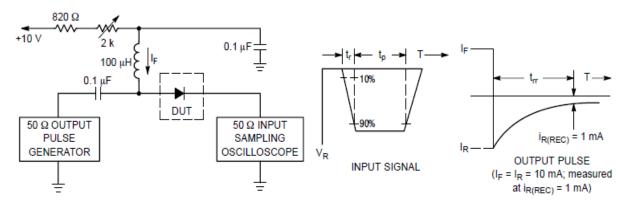
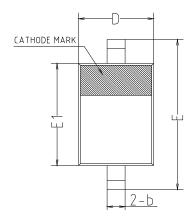
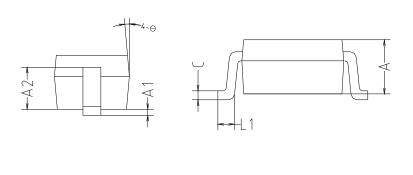


Fig. 5) Reverse recovery time equivalent test circuit



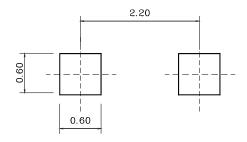
Package Outline Dimensions





SYMBOL	<u> </u>	NOTE		
	MINIMUM	NOMINAL	MAXIMUM	INOIL
А	0.850	-	0.950	
A1	0.000	-	0.100	
A 2	0.650	0.700	0.750	
Ь	0.250	0.300	0.350	
С	0.110	0.150	0.190	
D	1.200	1.250	1.300	
E	2.400	2.500	2.600	
E1	1.650	1.700	1.750	
L1	0.200	_	0.300	
Θ		5° REF		

****** Recommend PCB solder land (Unit : mm)



SDS19D

The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).

Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..

Specifications mentioned in this publication are subject to change without notice.